

STTH120L06TV

Turbo 2 ultrafast high voltage rectifier

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses

Description

The STTH120L06TV, which is using ST Turbo 2 600 V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and free-wheeling diode.

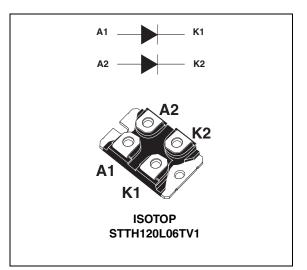


Table 1.Device summary

Symbol	Value			
I _{F(AV)}	2 x 60 A			
V _{RRM}	600 V			
Тj	150 °C			
V _F (typ)	0.95 V			
t _{rr} (max)	70 ns			

TM: ISOTOP is a trademark of STMicroelectronics

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage	600	V		
I _{F(RMS)}	RMS forward current	120	А		
I _{F(AV)}	Average forward current, $\delta = 0.5$	$T_c = 65^\circ C$	Per diode	60	А
I _{FSM}	Surge non repetitive forward current t _p = 10 ms Sinusoidal			500	А
T _{stg}	Storage temperature range	-55 to + 150	°C		
Тj	Maximum operating junction temperat		150	°C	

Table 3.Thermal parameter

Symbol	Parameter		Maximum	Unit
P	Junction to case	Per diode	0.98	
R _{th(j-c)}	Sufficient to case	Total		°C/W
R _{th(c)}	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th(j-c) (per diode)}} + P_{\text{(diode2)}} \times R_{\text{th(c)}}$

		(1					
Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
IR ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V V			50	μA	
	neverse leakage current	T _j = 125 °C	$V_{R} = V_{RRM}$		50	500	μΑ
V _E ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 60 A			1.55	V
V _F ⁽⁻⁾		$T_j = 150 \ ^\circ C$			0.95	1.20	v

 Table 4.
 Static electrical characteristics (per diode)

1. Pulse test: t_p = 5 ms, δ < 2 %

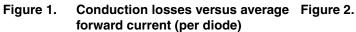
2. Pulse test: $t_p = 380 \ \mu s$, $\delta < 2 \ \%$

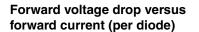
To evaluate the maximum conduction losses use the following equation: P = 0.93 x $I_{F(AV)}$ + 0.0045 I_{F}^{2} (RMS)

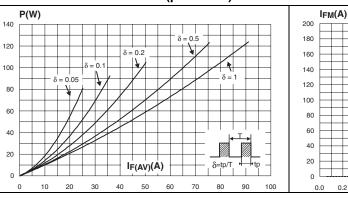


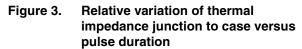
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
t _{rr} Reverse recovery time	T _j = 25 °C	$I_{F} = 0.5 \text{ A},$ $I_{rr} = 0.25 \text{ A},$ $I_{R} = 1 \text{ A}$			70	ns	
		I _F = 1 A, dI _F /dt = 50 A/μs, V _R = 30 V		75	105	ns	
I _{RM}	Reverse recovery current	T _j = 125 °C	I _F = 60 A, dI _F /dt = 400 A/μs, dI _F /dt = 100 A/μs		14	19	A
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$			500	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$		3		V

Dynamic characteristics (per diode) Table 5.





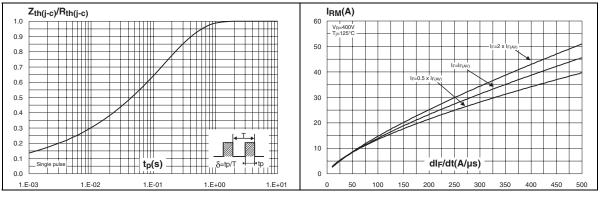






versus dl_F/dt (typical values, per diode)

1.8 2.0 2.2

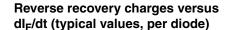


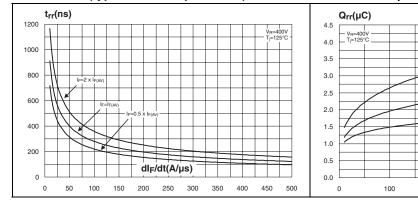
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500

400

Figure 5. Reverse recovery time versus dl_F/dt Figure 6. (typical values, per diode)





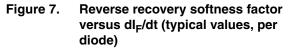


Figure 8. Relative variations of dynamic parameters versus junction temperature

200

IF=2

Ic-

IF=0.5

dl_F/dt(A/µs)

300

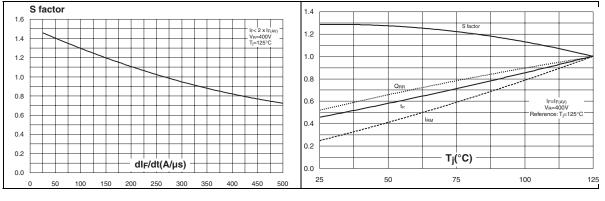
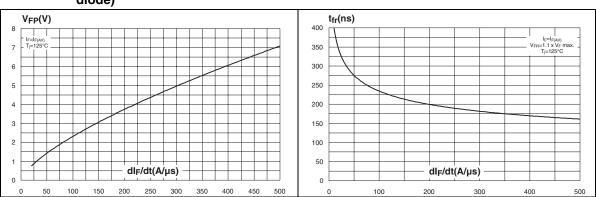


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)

Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)





	C(pF)
1000	F=1MHz V _{0SC} =20mV _{RMS} T ₁ =25°C
100	
100	
10	
	1 10 100 1000

Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)

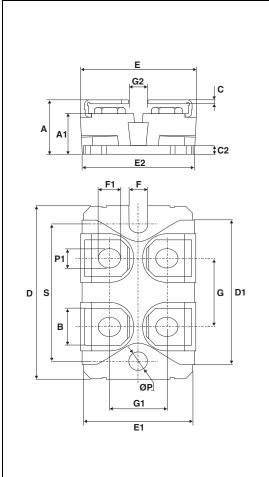


2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N·m

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Table 6. ISOTOP dimensions



	Dimensions				
Ref.	Millin	neters	Inches		
	Min.	Max.	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
Е	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.8	0 typ.	0.976 typ.		
G	14.90	15.10	0.587	0.594	
G1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH120L06TV1	STTH120L06TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

Table 8.Document revision history

Date	Revision	Changes	
07-Sep-2004	1	First issue.	
04-Apr-2011	2	Updated Chapter 2: Package information.	



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